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# 2SC5337

NPN Silicon RF Transistor for High-Frequency Low Distortion Amplifier 4-Pin Power Minimold

#### FEATURES

- Low distortion:  $IM_2 = 59.0 \text{ dB}$  TYP.,  $IM_3 = 82.0 \text{ dB}$  TYP. @ Vce = 10 V, Ic = 50 mA
- Low noise

NF = 1.5 dB TYP. @ Vce = 10 V, Ic = 50 mA, f = 500 MHz

- NF = 2.0 dB TYP. @ Vce = 10 V, Ic = 50 mA, f = 1 GHz
- 4-pin power minimold package with improved gain from the 2SC4536

#### <R> ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Supplying Form
2SC5337	2SC5337-AZ	4-pin power	25 pcs (Non reel)	Magazine case
2SC5337-T1	2SC5337-T1-AZ	minimold (Pb-Free) <sup>Note</sup>	1 kpcs/reel	<ul><li>12 mm wide embossed taping</li><li>Collector face the perforation side of the tape</li></ul>

Note Contains Lead in the part except the electrode terminals.

**Remark** To order evaluation samples, please contact your nearby sales office. Unit sample quantity is 25 pcs.

#### ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	30	V
Collector to Emitter Voltage	Vceo	15	V
Emitter to Base Voltage	Vebo	3.0	V
Collector Current	lc	250	mA
Total Power Dissipation	Ptot Note	2.0	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-65 to +150	°C

**Note** Mounted on 16  $\text{cm}^2 \times 0.7 \text{ mm}$  (t) ceramic substrate (Copper plating)

#### CAUTION

Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The mark <R> shows major revised points.

The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.



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#### <R> ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	Ісво	V <sub>CB</sub> = 20 V, I <sub>E</sub> = 0	_	0.01	5.0	μA
Emitter Cut-off Current	Іево	V <sub>BE</sub> = 2 V, Ic = 0	-	0.03	5.0	μA
DC Current Gain	hfe Note 1	Vce = 10 V, Ic = 50 mA	60	120	200	-
RF Characteristics						
Insertion Power Gain	S <sub>21e</sub>   <sup>2</sup>	Vce = 10 V, Ic = 50 mA, f = 1 GHz	7.0	8.3	-	dB
Noise Figure (1)	NF Note 2	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 50 mA, f = 500 MHz	-	1.5	3.5	dB
Noise Figure (2)	NF Note 2	Vce = 10 V, Ic = 50 mA, f = 1 GHz	-	2.0	3.5	dB
2nd Order Intermoduration Distortion	IM2		-	59.0	-	dB
3rd Order Intermoduration Distortion	IМз		-	82.0	-	dB

Notes 1. Pulse measurement: PW  $\leq 350~\mu s,$  Duty Cycle  $\leq 2\%$ 

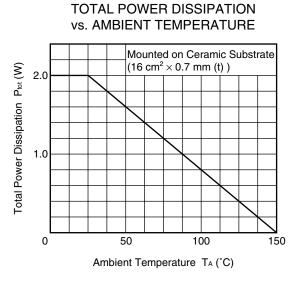
**2.** Rs = RL = 50  $\Omega$ , tuned

#### <R> hfe CLASSIFICATION

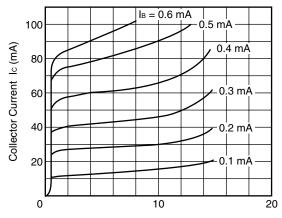
Rank	QR/YQR	QS/YQS	
Marking	QR	QS	
hfe Value	60 to 120	100 to 200	



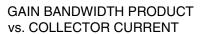
### **TYPICAL CHARACTERISTICS (Unless otherwise specified, TA = +25°C)**

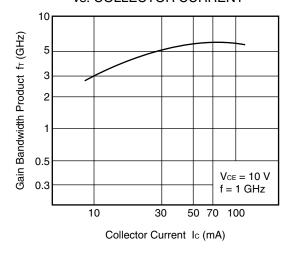


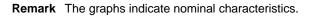
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE

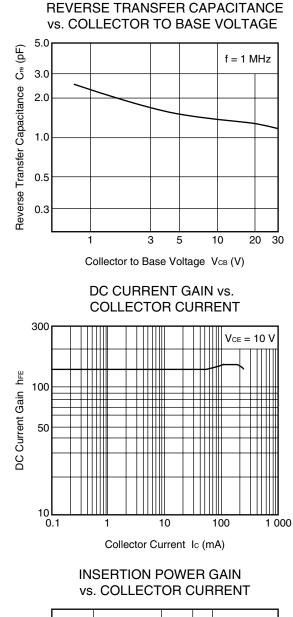


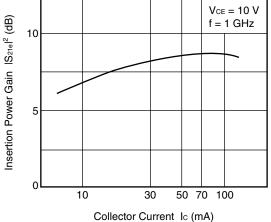
Collector to Emitter Voltage VCE (V)



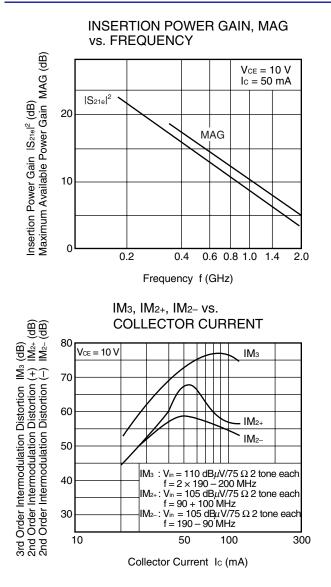


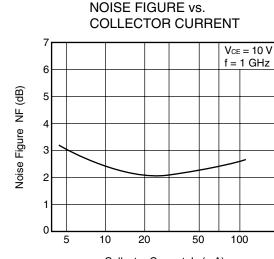






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Collector Current Ic (mA)

Remark The graphs indicate nominal characteristics.

#### <R> S-PARAMETERS

S-parameters and noise parameters are provided on our web site in a form (S2P) that enables direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.

Click here to download S-parameters.

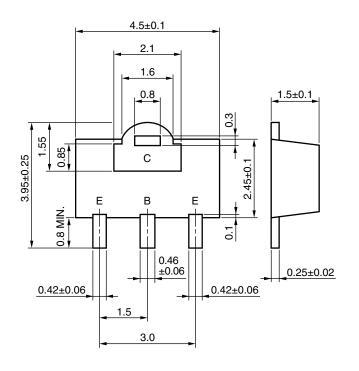
 $[\text{Products}] \rightarrow [\text{RF Devices}] \rightarrow [\text{Device Parameters}]$ 

URL http://www.renesas.com/products/microwave/



#### PACKAGE DIMENSIONS

#### 4-PIN POWER MINIMOLD (UNIT: mm)



#### **PIN CONNECTIONS**

- E: Emitter
- C: Collector
- B: Base

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**Revision History** 

### 2SC5337 Data Sheet

		Description		
Rev.	Date	Page	Summary	
1.00	Mar 01, 1996	-	First edition issued	
2.00	Aug 28, 2001	-	Second edition issued	
2.10	Sep 06, 2001	-	Second V1 edition issued	
3.00	Sep 14, 2012	Throughout	The company name is changed to Renesas Electronics Corporation.	
		p.1	Modification of ORDERING INFORMATION	
		p.2	Modification of ELECTRICAL CHARACTERISTICS	
		p.2	Modification of h <sub>FE</sub> CLASSIFICATION	
		p.4	Modification of method for obtaining S-parameters	

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